

KSA1015

LOW FREQUENCY AMPLIFIER

- Collector-Base Voltage : V_{CBO}= -50V WWW.BZSC.COM
- Complement to KSC1815



1. Emitter 2. Collector 3. Base NWW.DZSC.CO

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V_{CBO}	Collector-Base Voltage	-50	V	
V _{CEO}	Collector-Emitter Voltage	-50	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current	-150	mA	
I _B	Base Current	-50	mA	
P _C	Collector Power Dissipation	400	mW	
T _J	Junction Temperature	125	°C	
T _{ST9}	Storage Temperature	-65 ~ 150	°C	

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = -100 \mu A, I_{E} = 0$	-50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA, I _B =0	-50			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	-5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -50V, I_{E} = 0$			-0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} = -5V, I_{C} =0			-0.1	μΑ
h _{FE1}	DC Current Gain	V _{CE} = -6V, I _C = -2mA	70		400	73.7
h_{FE2}		$V_{CE} = -6V, I_{C} = -150 \text{mA}$	25		-11	2.00
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -100mA, I _B = -10mA		-0.1	-0.3	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I_{C} = -100mA, I_{B} = -10mA		W.W.	-1.1	V
f _T	Current Gain Bandwidth Product	V _{CE} = -10V, I _C =-1mA	80	7,-11-11		MHz
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0, f=1MHz		4	7	pF
NF	Noise Figure	V_{CE} = -6V, I_{C} = -0.1mA f=100Hz, R_{G} =10k Ω		0.5	6	dB

1=100112, 11(3=10132							
h _{FE} Classification							
Classification	0	Υ	GR				
h _{FE1}	70 ~ 140	120 ~ 240	200 ~ 400				

Typical Characteristics

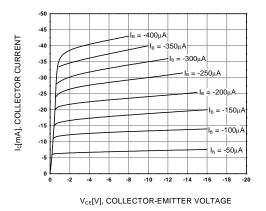


Figure 1. Static Characteristic

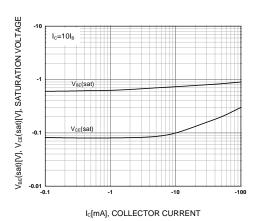


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

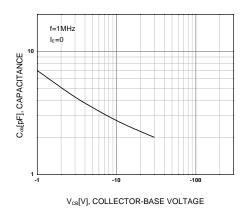


Figure 5. Collector Output Capacitance

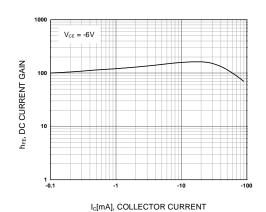


Figure 2. DC current Gain

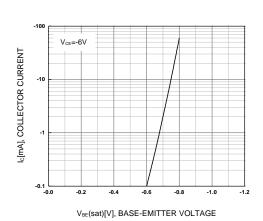


Figure 4. Base-Emitter On Voltage

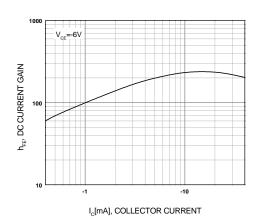
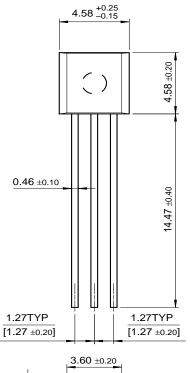


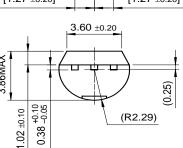
Figure 6. Current Gain Bandwidth Product

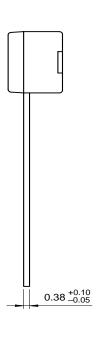
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Package Dimensions

TO-92







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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